L Number	Hits	Search Text	DB	Time stamp
1	283	438/677	USPAT	2003/07/11 09:17
-	655	semiconduct$3 and electr$5 and (target or substrate or wafer or sample) and (charge near2 separation)	USPAT; US-PGPUB	2003/07/08 16:30
-	317	(semiconduct$3 and electr$5 and (target or substrate or wafer or sample) and (charge near2 separation)) and molecule	USPAT; US-PGPUB	2003/07/08 10:16
-	246	((semiconduct$3 and electr$5 and (target or substrate or wafer or sample) and (charge near2 separation)) and molecule) and electronic	USPAT; US-PGPUB	2003/07/08 10:17
-	106	(((semiconduct$3 and electr$5 and (target or substrate or wafer or sample) and (charge near2 separation)) and molecule) and electronic) and (electronic same molecule)	USPAT; US-PGPUB	2003/07/08 10:17
-	46	((((semiconduct$3 and electr$5 and (target or substrate or wafer or sample) and (charge near2 separation)) and molecule) and electronic) and (electronic same molecule)) and amp$7	USPAT; US-PGPUB	2003/07/08 10:18
-	149	(((semiconduct$3 and electr$5 and (target or substrate or wafer or sample) and (charge near2 separation)) and molecule) and electronic) and signal$4	USPAT; US-PGPUB	2003/07/08 10:30
-	65	(((semiconduct$3 and electr$5 and (target or substrate or wafer or sample) and (charge near2 separation)) and molecule) and electronic) and ((charge near2 separation) same semiconduct$4)	USPAT; US-PGPUB	2003/07/09 09:06
-	0	semiconduct$3 and electr$5 and (target or substrate or wafer or sample) and (prolong$3 near8 (charge near2 separation))	USPAT; US-PGPUB	2003/07/08 16:30
-	1	(prolong$3 near8 (charge near2 separation))	USPAT; US-PGPUB	2003/07/08 16:31
-	0	paunesku-tatjana.in.	USPAT; US-PGPUB	2003/07/08 16:32
-	0	woloschak-gayle.in.	USPAT; US-PGPUB	2003/07/08 16:32
-	0	woloschak.in.	USPAT; US-PGPUB	2003/07/08 16:32
-	4	thurnauer-marion.in.	USPAT; US-PGPUB	2003/07/08 16:32
-	1	paunesku.in.	USPAT; US-PGPUB	2003/07/08 16:35
-	3	rajh-tijana.in.	USPAT; US-PGPUB	2003/07/08 16:38
-	261	octahedral same metal same oxide	USPAT; US-PGPUB	2003/07/08 16:39
-	30	octahedral near5 metal near5 oxide	USPAT; US-PGPUB	2003/07/08 17:03
-	16	semiconductor same (charge near2 separat$4) same molecule	USPAT; US-PGPUB	2003/07/08 17:04
-	100	(charge near2 separation) near6 molecule	USPAT; US-PGPUB	2003/07/09 09:07
-	46	((charge near2 separation) near6 molecule) and semiconduct$3	USPAT; US-PGPUB	2003/07/09 09:41
-	10	bidentate adj moiet$3	USPAT; US-PGPUB	2003/07/09 09:49
-	5917	cleav$3 near2 molecule	USPAT; US-PGPUB	2003/07/09 09:49
-	184	(cleav$3 near2 molecule) and semiconductor	USPAT; US-PGPUB	2003/07/09 10:52
-	98	((cleav$3 near2 molecule) and semiconductor) and oxidat$4	USPAT; US-PGPUB	2003/07/09 10:53
-	74	(((cleav$3 near2 molecule) and semiconductor) and oxidat$4) and energ$3	USPAT; US-PGPUB	2003/07/09 10:53

-	4	(((((cleav$3 near2 molecule) and semiconductor) and oxidat$4) and energ$3) and electric$3) and (energy near5 level)	USPAT; US-PGPUB	2003/07/09 10:56
-	64	((((cleav$3 near2 molecule) and semiconductor) and oxidat$4) and energ$3) and electric$3	USPAT; US-PGPUB	2003/07/09 13:24
-	3	(US-5506420-$ or US-6545290-$ or US-6271130-$).did.	USPAT	2003/07/10 10:36
-	677	250/251	USPAT; US-PGPUB	2003/07/09 17:29
-	507	250/328	USPAT; US-PGPUB	2003/07/09 17:29
-	173	250/315.3	USPAT; US-PGPUB	2003/07/09 17:29
-	2035	250/307	USPAT; US-PGPUB	2003/07/09 17:29
-	686	250/302	USPAT; US-PGPUB	2003/07/09 17:29
-	1247	250/459.1	USPAT; US-PGPUB	2003/07/09 17:29
-	1114	257/40	USPAT	2003/07/10 10:37
-	351	257/102	USPAT	2003/07/10 10:37
-	1240	257/103	USPAT	2003/07/10 10:37
-	107	257/228	USPAT	2003/07/10 10:37